NSN 5962-01-460-5464

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-40.0/+85.0 degrees celsius
Features Provided:
Electrostatic sensitive
Inclosure Configuration:
Dual-in-line
Criticality Code Justification:
Cbbl
Product Name:
4 megabit (512k x 8 or 256k x 16), 5.0 v- only sector erase flash memory
Voltage Rating And Type Per Characteristic:
-2.0 volts applied and 7.0 volts applied
Memory Device Type:
Earom
Terminal Type And Quantity:
44 flat leads
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0